



Dr. Dong-Seok Kim

(Korea Atomic Energy Research Institute, Republic
of Korea)



Dong-Seok Kim was received the B.S., the M.S., and the Ph.D degrees in electronics engineering from Kyungpook National University (KNU), Republic of Korea, in 2008, 2010, and 2015, respectively. His doctoral research concerned the growth of III-nitride epitaxial structure and the fabrication of GaN-based devices. He is currently a senior researcher of Korea Atomic Energy Research Institute (KAERI). His research is focused on the cosmic-ray radiation effects on semiconductor devices such as HEMT, MOSFET, etc., for RF and power applications.